TOSHIBA Transistor Silicon NPN Epitaxial (PCT process)

2SC2859

Audio Frequency Low Power Amplifier Applications
Driver Stage Amplifier Applications
Switching Applications

- Excellent hFE linearity: hFE (2) = 25 (min) (VCE = 6 V, IC = 400 mA)
- Complementary to 2SA1182.

Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Collector-base voltage	V_{CBO}	35	٧
Collector-emitter voltage	V _{CEO}	30	٧
Emitter-base voltage	V _{EBO}	5	٧
Collector current	IC	500	mA
Base current	Ι _Β	50	mA
Collector power dissipation	P _C	150	mW
Junction temperature	Tj	125	°C
Storage temperature range	T _{stg}	-55~125	°C

1. BASE 2. EMITTER 3. COLLECTOR JEDEC TO-236MOD JEITA SC-59 TOSHIBA 2-3F1A

Weight: 0.012 g (typ.)

Electrical Characteristics (Ta = 25°C)

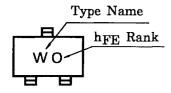
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I _{CBO}	$V_{CB} = 35 \text{ V}, I_E = 0$	_	_	0.1	μА
Emitter cut-off current	I _{EBO}	V _{EB} = 5 V, I _C = 0		_	0.1	μΑ
DC current gain (Note)	h _{FE (1)}	V _{CE} = 1 V, I _C = 100 mA	70	_	400	
	h _{FE} (2)	V _{CE} = 6 V, I _C = 400 mA	25	_	_	
Collector-emitter saturation voltage	V _{CE} (sat)	$I_C = 100 \text{ mA}, I_B = 10 \text{ mA}$	_	0.1	0.25	V
Base-emitter voltage	V _{BE}	V _{CE} = 1 V, I _C = 100 mA	_	0.8	1.0	V
Transition frequency	f _T	V _{CE} = 6 V, I _C = 20 mA	_	300	_	MHz
Collector output capacitance	C _{ob}	$V_{CB} = 6 \text{ V}, I_{E} = 0, f = 1 \text{ MHz}$	_	7	_	pF

Note: hFE (1) classification O (O): 70~140, Y (Y): 120~240, GR (G): 200~400

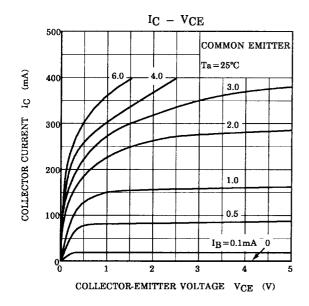
hFE (2) classification O: 25 min, Y: 40 min, GR: 70 min

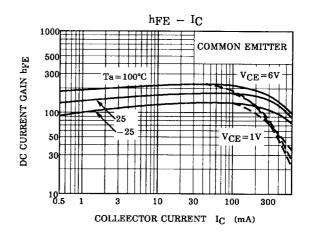
() marking symbol

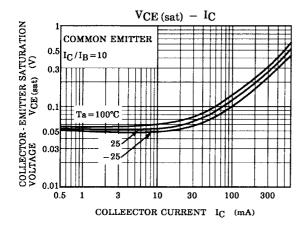
Marking

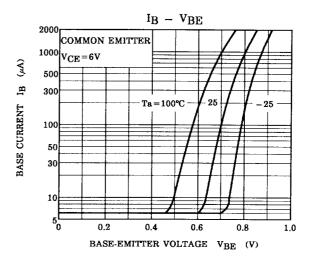


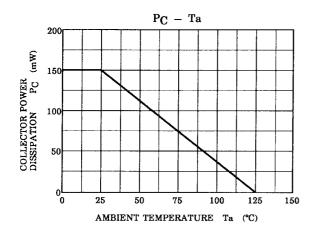
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